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ON Semiconductor BAV99LT1

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**Distributor of ON Semiconductor: Excellent Integrated System Limited** Datasheet of BAV99LT1 - DIODE ARRAY GP 70V 215MA SOT23-3 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

# BAV99LT1

Preferred Device

# **Dual Series** Switching Diode

### MAXIMUM RATINGS (Each Diode)

Rating	Symbol	Value	Unit	
Reverse Voltage	V <sub>R</sub>	70	Vdc	
Forward Current	١ <sub>F</sub>	215	mAdc	
Peak Forward Surge Current	I <sub>FM(surge)</sub>	500	mAdc	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	70	V	
Average Rectified Forward Current (Note 1.) (averaged over any 20 ms period)	I <sub>F(AV)</sub>	715	mA	
Repetitive Peak Forward Current	I <sub>FRM</sub>	450	mA	
Non–Repetitive Peak Forward Current $t = 1.0 \ \mu s$ $t = 1.0 \ ms$ $t = 1.0 \ S$	I <sub>FSM</sub>	2.0 1.0 0.5	A	

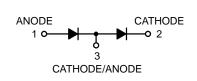
#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 1.) $T_{A} = 25^{\circ}C$	PD	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2.) $T_A = 25^{\circ}C$	P <sub>D</sub>	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–65 to +150	°C



# **ON Semiconductor**

http://onsemi.com





A7 M

**MARKING DIAGRAM** 

SOT-23 STYLE 11

A7 = Device Code M = Date Code

### ORDERING INFORMATION

Device	Package	Shipping	
BAV99LT1	SOT-23	3000/Tape & Reel	

Preferred devices are recommended choices for future use and best overall value.

### **OFF CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Each Diode)

Characteristic	Symbol	Min	Max	Unit
Reverse Breakdown Voltage ( $I_{(BR)}$ = 100 µA)	V <sub>(BR)</sub>	70	-	Vdc
$ \begin{array}{ll} \mbox{Reverse Voltage Leakage Current} & (V_R = 70 \mbox{ Vdc}) \\ & (V_R = 25 \mbox{ Vdc},  T_J = 150^\circ\mbox{C}) \\ & (V_R = 70 \mbox{ Vdc},  T_J = 150^\circ\mbox{C}) \end{array} $	I <sub>R</sub>	- - -	2.5 30 50	μAdc
Diode Capacitance ( $V_R = 0$ , f = 1.0 MHz)	CD	-	1.5	pF
Forward Voltage $(I_F = 1.0 \text{ mAdc})$ $(I_F = 10 \text{ mAdc})$ $(I_F = 50 \text{ mAdc})$ $(I_F = 150 \text{ mAdc})$	V <sub>F</sub>	- - - -	715 855 1000 1250	mVdc
Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 10 mAdc, $i_{R(REC)}$ = 1.0 mAdc) (Figure 1) R <sub>L</sub> = 100 $\Omega$	t <sub>rr</sub>	-	6.0	ns
Forward Recovery Voltage ( $I_F$ = 10 mA, $t_r$ = 20 ns)	V <sub>FR</sub>	_	1.75	V

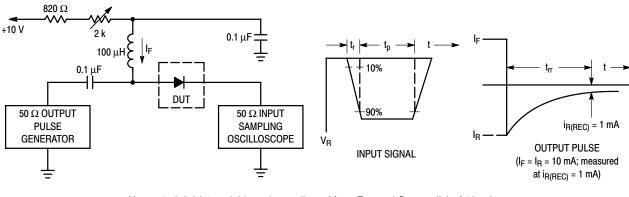
1. FR–5 = 1.0  $\times$  0.75  $\times$  0.062 in.

2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



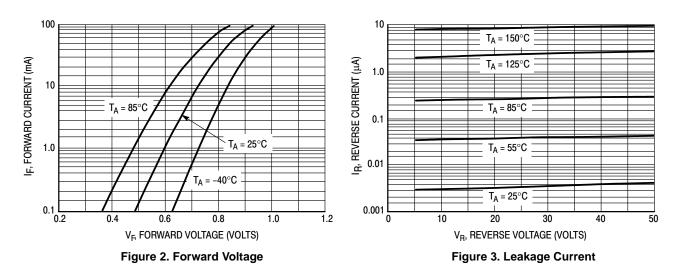
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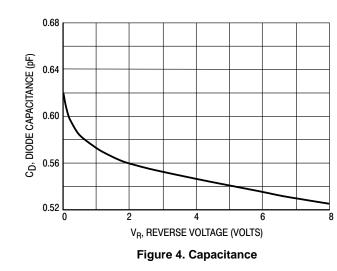


Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA. 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA. 3.  $t_p$  »  $t_{rr}$ 

Figure 1. Recovery Time Equivalent Test Circuit



### CURVES APPLICABLE TO EACH DIODE



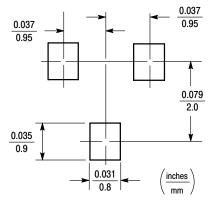


# BAV99LT1

# INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

#### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.





#### **SOT-23 POWER DISSIPATION**

The power dissipation of the SOT-23 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by T<sub>J(max)</sub>, the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature, T<sub>A</sub>. Using the values provided on the data sheet for the SOT-23 package, PD can be calculated as follows:

$$P_{D} = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values

#### SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.

into the equation for an ambient temperature T<sub>A</sub> of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$\mathsf{P}_{\mathsf{D}} = \frac{150^\circ \mathsf{C} - 25^\circ \mathsf{C}}{556^\circ \mathsf{C}/\mathsf{W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad<sup>™</sup>. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

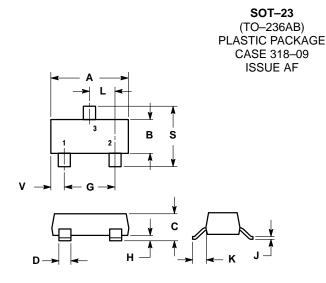
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.



# BAV99LT1

#### PACKAGE DIMENSIONS



NOTES 1. DIMEINS. Y14.5M, 1982. DIMENSIONING AND TOLERANCING PER ANSI 2. CONTROLING DIMENSION: INCH. 3. MAXIUMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. INCHES MIN MAX MILLIMETERS DIM MIN MAX A 0.1102 0.1197 B 0.0472 0.0551 2.80 3.04 1.20 1.40 
 C
 0.0385
 0.0498

 D
 0.0140
 0.0200
0.99 1.26 0.36 0.50 G 0.0670 0.0826 1.70 2.10 H 0.0040 0.0098 0.10 0.25 J 0.0034 0.0070 K 0.0180 0.0236 0.085 0.177 0.45 0.60 0.0350 0.0401 0.0830 0.0984 0.89 1.02 
 S
 0.0830
 0.021

 V
 0.0177
 0.0236
2.50 2.10 0.45 0.60 STYLE 11: PIN 1. ANODE

2. CATHODE 3. CATHODE-ANODE

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